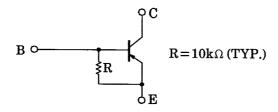
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

RN6003

Motor Drive Circuit Applications
Power Amplifier Applications
Power Switching Applications

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Small flat package
- PC = 1~2W (mounted on ceramic substrate)
- Complementary to RN5003

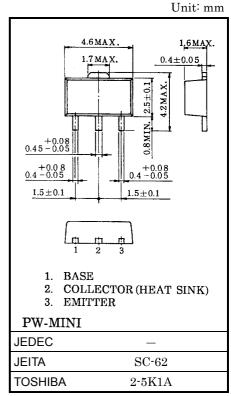
Equivalent Circuit



Maximum Ratings (Ta = 25°C)

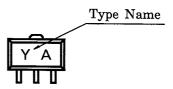
Characteristic	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	-30	V
Collector-emitter voltage	V _{CES}	-30	V
Emitter-base voltage	V _{EBO}	-5	V
Collector current	IC	-2	Α
Base current	ΙB	-0.4	Α
Collector power dissipation	PC	500	mW
Collector power dissipation	P _C *	1000	mW
Junction temperature	Tj	150	°C
Storage temperature range	T _{stg}	-55~150	°C

^{* :} Mounterd on ceramic substrate (250mm $^2 \times 0.8t$)



Weight: 0.05g (typ.)

Marking



Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	_	$V_{CB} = -30V$, $I_{E} = 0$	_	_	-0.1	μΑ
Emitter cut-off current	I _{EBO}	_	$V_{EB} = -5V$, $I_C = 0$	-0.385	-0.50	-0.714	mA
Collector-emitter breakdown voltage	V _{(BR)CES}	_	I _C = −10mA	-30	-	_	V
DC current gain	h _{FE (1)}	_	$V_{CE} = -2V$, $I_{C} = -0.5A$	100	1	400	_
	h _{FE (2)}		$V_{CE} = -2V$, IC = -2.0A	30	-	_	
Collector-emitter saturation voltage	V _{CE} (sat)	_	$I_C = -1A$, $I_B = -0.05A$	_	1	-0.5	V
Base-emitter saturation voltage	V _{BE (sat)}	_	$I_C = -1A$, $I_B = -0.05A$	_	1	-1.2	V
Transition frequency	f _T	_	$V_{CE} = -2V$, $I_{C} = -0.5A$	_	120		MHz
Collector output capacitance	C _{ob}	_	$V_{CB} = -10V$, $I_E = 0$, $f = 1 \text{ MHz}$	_	40	_	pF
Resistor	R	_	_	7	10	13	kΩ

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